

# MC74VHC1G50

## Buffer

The MC74VHC1G50 is an advanced high speed CMOS buffer fabricated with silicon gate CMOS technology. It achieves high speed operation similar to equivalent Bipolar Schottky TTL while maintaining CMOS low power dissipation.

The internal circuit is composed of three stages, including a buffered output which provides high noise immunity and stable output.

The MC74VHC1G50 input structure provides protection when voltages up to 7.0 V are applied, regardless of the supply voltage. This allows the MC74VHC1G50 to be used to interface 5.0 V circuits to 3.0 V circuits.

- High Speed:  $t_{PD} = 3.5 \text{ ns}$  (Typ) at  $V_{CC} = 5 \text{ V}$
- Low Power Dissipation:  $I_{CC} = 1 \mu\text{A}$  (Max) at  $T_A = 25^\circ\text{C}$
- Power Down Protection Provided on Inputs
- Balanced Propagation Delays
- Pin and Function Compatible with Other Standard Logic Families
- Chip Complexity: FET = 104; Equivalent Gate = 26
- **These devices are available in Pb-free package(s). Specifications herein apply to both standard and Pb-free devices. Please see our website at [www.onsemi.com](http://www.onsemi.com) for specific Pb-free orderable part numbers, or contact your local ON Semiconductor sales office or representative.**

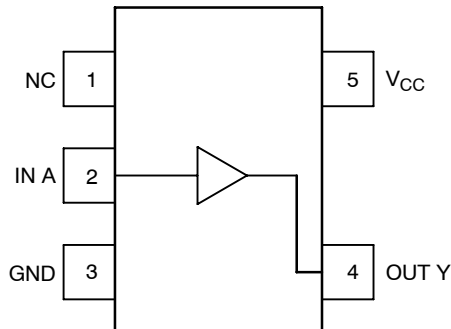


Figure 1. Pinout (Top View)

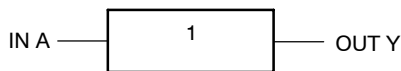


Figure 2. Logic Symbol



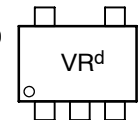
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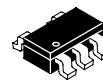
### MARKING DIAGRAMS



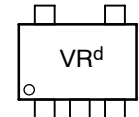
SC-88A / SOT-353/SC-70  
DF SUFFIX  
CASE 419A



Pin 1  
d = Date Code



TSOP-5/SOT-23/SC-59  
DT SUFFIX  
CASE 483



Pin 1  
d = Date Code

### PIN ASSIGNMENT

| Pin | Assignment |
|-----|------------|
| 1   | NC         |
| 2   | IN A       |
| 3   | GND        |
| 4   | OUT Y      |
| 5   | $V_{CC}$   |

### FUNCTION TABLE

| A Input | Y Output |
|---------|----------|
| L       | L        |
| H       | H        |

### ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 4 of this data sheet.

# MC74VHC1G50

## MAXIMUM RATINGS (Note 1)

| Symbol                | Characteristics                            | Value  | Unit                   |
|-----------------------|--|--|------------------------|
| V <sub>CC</sub>       | DC Supply Voltage                          | -0.5 to +7.0   | V                      |
| V <sub>IN</sub>       | DC Input Voltage                           | -0.5 to +7.0   | V                      |
| V <sub>OUT</sub>      | DC Output Voltage                          | V <sub>CC</sub> = 0<br>High or Low State<br>-0.5 to 7.0<br>-0.5 to V <sub>CC</sub> + 0.5 | V                      |
| I <sub>IK</sub>       | Input Diode Current                        | -20  | mA                     |
| I <sub>OK</sub>       | Output Diode Current                       | V <sub>OUT</sub> < GND; V <sub>OUT</sub> > V <sub>CC</sub>                               | mA                     |
| I <sub>OUT</sub>      | DC Output Current, per Pin                 | +25  | mA                     |
| I <sub>CC</sub>       | DC Supply Current, V <sub>CC</sub> and GND | +50  | mA                     |
| P <sub>D</sub>        | Power dissipation in still air             | SC-88A, TSOP-5   | mW                     |
| θ <sub>JA</sub>       | Thermal resistance                         | SC-88A, TSOP-5   | °C/W                   |
| T <sub>L</sub>        | Lead temperature, 1 mm from case for 10 s  | 260  | °C                     |
| T <sub>J</sub>        | Junction temperature under bias            | +150   | °C                     |
| T <sub>stg</sub>      | Storage temperature                        | -65 to +150  | °C                     |
| V <sub>ESD</sub>      | ESD Withstand Voltage                      | Human Body Model (Note 2)<br>Machine Model (Note 3)<br>Charged Device Model (Note 4)     | > 2000<br>> 200<br>N/A |
| I <sub>Latch-Up</sub> | Latch-Up Performance                       | Above V <sub>CC</sub> and Below GND at 125°C (Note 5)                                    | ±500                   |

- Maximum Ratings are those values beyond which damage to the device may occur. Exposure to these conditions or conditions beyond those indicated may adversely affect device reliability. Functional operation under absolute-maximum-rated conditions is not implied. Functional operation should be restricted to the Recommended Operating Conditions.
- Tested to EIA/JESD22-A114-A
- Tested to EIA/JESD22-A115-A
- Tested to JESD22-C101-A
- Tested to EIA/JESD78

## RECOMMENDED OPERATING CONDITIONS

| Symbol                          | Characteristics             | Min  | Max             | Unit |
|---------------------------------|-----------------------------|--|-----------------|------|
| V <sub>CC</sub>                 | DC Supply Voltage           | 2.0  | 5.5             | V    |
| V <sub>IN</sub>                 | DC Input Voltage            | 0.0  | 5.5             | V    |
| V <sub>OUT</sub>                | DC Output Voltage           | 0.0  | V <sub>CC</sub> | V    |
| T <sub>A</sub>                  | Operating Temperature Range | -55  | +125            | °C   |
| t <sub>r</sub> , t <sub>f</sub> | Input Rise and Fall Time    | V <sub>CC</sub> = 3.3 V ± 0.3 V<br>V <sub>CC</sub> = 5.0 V ± 0.5 V | 0<br>100<br>20  | ns/V |

## Device Junction Temperature versus Time to 0.1% Bond Failures

| Junction Temperature °C | Time, Hours | Time, Years |
|-------------------------|-------------|-------------|
| 80                      | 1,032,200   | 117.8       |
| 90                      | 419,300     | 47.9        |
| 100                     | 178,700     | 20.4        |
| 110                     | 79,600      | 9.4         |
| 120                     | 37,000      | 4.2         |
| 130                     | 17,800      | 2.0         |
| 140                     | 8,900       | 1.0         |

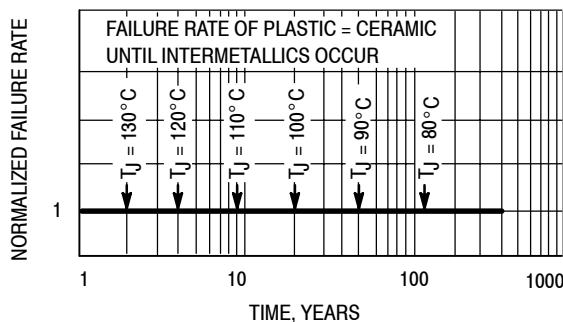


Figure 3. Failure Rate vs. Time Junction Temperature

# MC74VHC1G50

## DC ELECTRICAL CHARACTERISTICS

| Symbol          | Parameter   | Test Conditions  | V <sub>CC</sub> (V) | T <sub>A</sub> = 25°C |      |      | T <sub>A</sub> ≤ 85°C |      | -55 ≤ T <sub>A</sub> ≤ 125°C |      | Unit |   |
|-----------------|---|--|---------------------|-----------------------|------|------|-----------------------|------|------------------------------|------|------|---|
|                 |   |  |                     | Min                   | Typ  | Max  | Min                   | Max  | Min                          | Max  |      |   |
| V <sub>IH</sub> | Minimum High-Level Input Voltage  |  | 2.0                 | 1.5                   |      |      | 1.5                   |      | 1.5                          |      | V    |   |
|                 |   |  | 3.0                 | 2.1                   |      |      | 2.1                   |      | 2.1                          |      |      |   |
|                 |   |  | 4.5                 | 3.15                  |      |      | 3.15                  |      | 3.15                         |      |      |   |
|                 |   |  | 5.5                 | 3.85                  |      |      | 3.85                  |      | 3.85                         |      |      |   |
| V <sub>IL</sub> | Maximum Low-Level Input Voltage   |  | 2.0                 |                       |      | 0.5  |                       | 0.5  |                              | 0.5  | V    |   |
|                 |   |  | 3.0                 |                       |      | 0.9  |                       | 0.9  |                              | 0.9  |      |   |
|                 |   |  | 4.5                 |                       |      | 1.35 |                       | 1.35 |                              | 1.35 |      |   |
|                 |   |  | 5.5                 |                       |      | 1.65 |                       | 1.65 |                              | 1.65 |      |   |
| V <sub>OH</sub> | Minimum High-Level Output Voltage<br>V <sub>IN</sub> = V <sub>IH</sub> or V <sub>IL</sub> | V <sub>IN</sub> = V <sub>IH</sub> or V <sub>IL</sub><br>I <sub>OH</sub> = -50 μA                           | 2.0                 | 1.9                   | 2.0  |      | 1.9                   |      | 1.9                          |      | V    |   |
|                 |   |  | 3.0                 | 2.9                   | 3.0  |      | 2.9                   |      | 2.9                          |      |      |   |
|                 |   | V <sub>IN</sub> = V <sub>IH</sub> or V <sub>IL</sub><br>I <sub>OH</sub> = -4 mA<br>I <sub>OH</sub> = -8 mA | 4.5                 | 4.4                   | 4.5  |      | 4.4                   |      | 4.4                          |      | 4.4  | V |
|                 |   |  | 3.0                 | 2.58                  |      |      | 2.48                  |      | 2.34                         |      | 2.34 |   |
| V <sub>OL</sub> | Maximum Low-Level Output Voltage<br>V <sub>IN</sub> = V <sub>IH</sub> or V <sub>IL</sub>  | V <sub>IN</sub> = V <sub>IH</sub> or V <sub>IL</sub><br>I <sub>OL</sub> = 50 μA                            | 2.0                 |                       | 0.0  | 0.1  |                       | 0.1  |                              | 0.1  | V    |   |
|                 |   |  | 3.0                 |                       | 0.0  | 0.1  |                       | 0.1  |                              | 0.1  |      |   |
|                 |   | V <sub>IN</sub> = V <sub>IH</sub> or V <sub>IL</sub><br>I <sub>OL</sub> = 4 mA<br>I <sub>OL</sub> = 8 mA   | 4.5                 |                       | 0.0  | 0.1  |                       | 0.1  |                              | 0.1  | 0.1  | V |
|                 |   |  | 3.0                 |                       |      | 0.36 |                       | 0.44 |                              | 0.52 | 0.52 |   |
| 4.5             |   |  | 0.36                |                       | 0.44 |      | 0.44                  |      | 0.52                         |      |      |   |
|                 |   |  |                     |                       |      |      |                       |      |                              |      |      |   |
| I <sub>IN</sub> | Maximum Input Leakage Current   | V <sub>IN</sub> = 5.5 V or GND   | 0 to 5.5            |                       |      | ±0.1 |                       | ±1.0 |                              | ±1.0 | μA   |   |
| I <sub>CC</sub> | Maximum Quiescent Supply Current  | V <sub>IN</sub> = V <sub>CC</sub> or GND   | 5.5                 |                       |      | 1.0  |                       | 20   |                              | 40   | μA   |   |

## AC ELECTRICAL CHARACTERISTICS C<sub>load</sub> = 50 pF, Input t<sub>r</sub> = t<sub>f</sub> = 3.0 ns

| Symbol                                 | Parameter  | Test Conditions  | T <sub>A</sub> = 25°C |     |      | T <sub>A</sub> ≤ 85°C |      | -55 ≤ T <sub>A</sub> ≤ 125°C |      | Unit |
|--|--|--|-----------------------|-----|------|-----------------------|------|------------------------------|------|------|
|  |  |  | Min                   | Typ | Max  | Min                   | Max  | Min                          | Max  |      |
| t <sub>PLH</sub> ,<br>t <sub>PHL</sub> | Maximum Propagation Delay,<br>Input A to $\bar{Y}$ | V <sub>CC</sub> = 3.3 ± 0.3 V C <sub>L</sub> = 15 pF<br>C <sub>L</sub> = 50 pF |                       | 4.5 | 7.1  |                       | 8.5  |                              | 10.0 | ns   |
|  |  |  |                       | 6.4 | 10.6 |                       | 12.0 |                              | 14.5 |      |
|  |  | V <sub>CC</sub> = 5.0 ± 0.5 V C <sub>L</sub> = 15 pF<br>C <sub>L</sub> = 50 pF |                       | 3.5 | 5.5  |                       | 6.5  |                              | 8.0  |      |
|  |  |  |                       | 4.5 | 7.5  |                       | 8.5  |                              | 10.0 |      |
| C <sub>IN</sub>                        | Maximum Input Capacitance                          |  |                       | 4   | 10   |                       | 10   |                              | 10   | pF   |

| C <sub>PD</sub> | Power Dissipation Capacitance (Note 6) | Typical @ 25°C, V <sub>CC</sub> = 5.0 V |  |
|-----------------|--|---|--|
|                 |  | 8.0                                     |  |
|                 |  | pF                                      |  |

6. C<sub>PD</sub> is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load. Average operating current can be obtained by the equation: I<sub>CC(OPR)</sub> = C<sub>PD</sub> • V<sub>CC</sub> • f<sub>in</sub> + I<sub>CC</sub>. C<sub>PD</sub> is used to determine the no-load dynamic power consumption; P<sub>D</sub> = C<sub>PD</sub> • V<sub>CC</sub><sup>2</sup> • f<sub>in</sub> + I<sub>CC</sub> • V<sub>CC</sub>.

# MC74VHC1G50

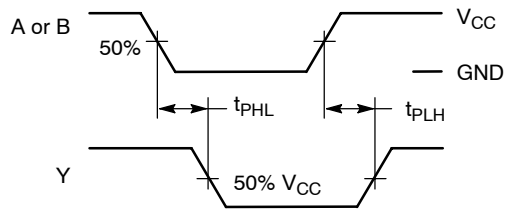
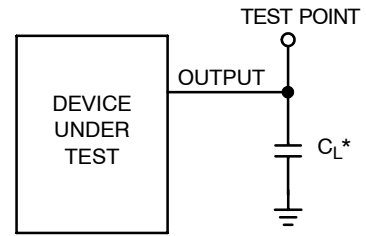


Figure 4. Switching Waveforms



\*Includes all probe and jig capacitance

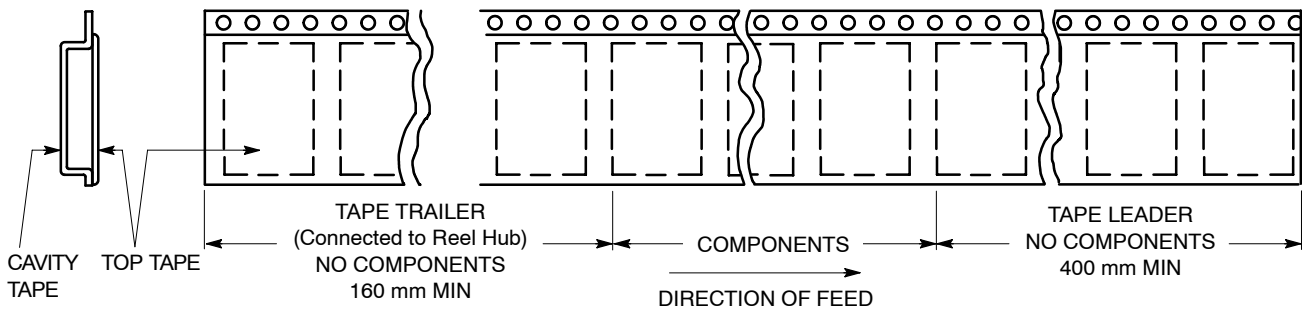
Figure 5. Test Circuit

## DEVICE ORDERING INFORMATION

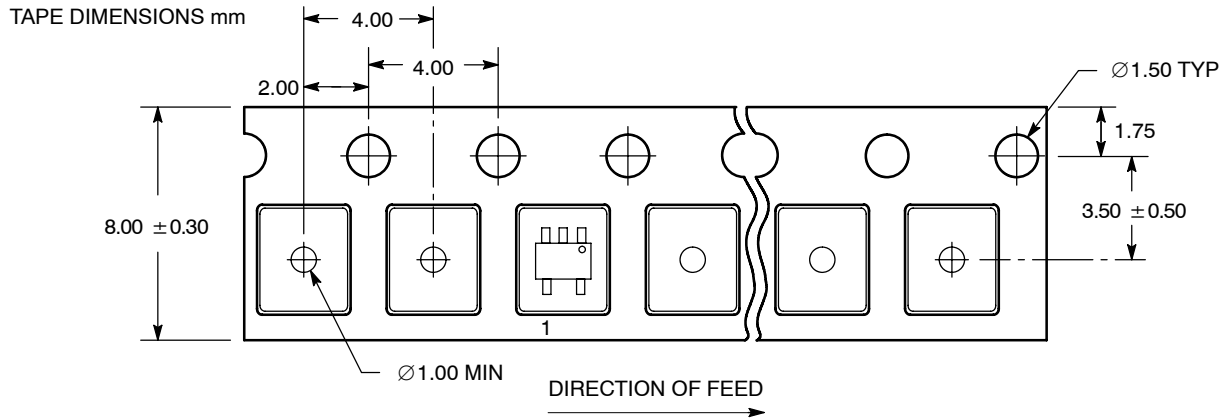
| Device Order Number | Device Nomenclature |                       |            |                 |                |                    | Package Type             | Tape and Reel Size†      |
|---------------------|---------------------|-----------------------|------------|-----------------|----------------|--------------------|--------------------------|--------------------------|
|                     | Circuit Indicator   | Temp Range Identifier | Technology | Device Function | Package Suffix | Tape & Reel Suffix |                          |                          |
| MC74VHC1G50DFT1     | MC                  | 74                    | VHC1G      | 50              | DF             | T1                 | SC-88A / SOT-353 / SC-70 | 178 mm (7")<br>3000 Unit |
| MC74VHC1G50DFT2     | MC                  | 74                    | VHC1G      | 50              | DF             | T2                 | SC-88A / SOT-353 / SC-70 | 178 mm (7")<br>3000 Unit |
| MC74VHC1G50DTT1     | MC                  | 74                    | VHC1G      | 50              | DT             | T1                 | TSOP-5 / SOT-23 / SC-59  | 178 mm (7")<br>3000 Unit |

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

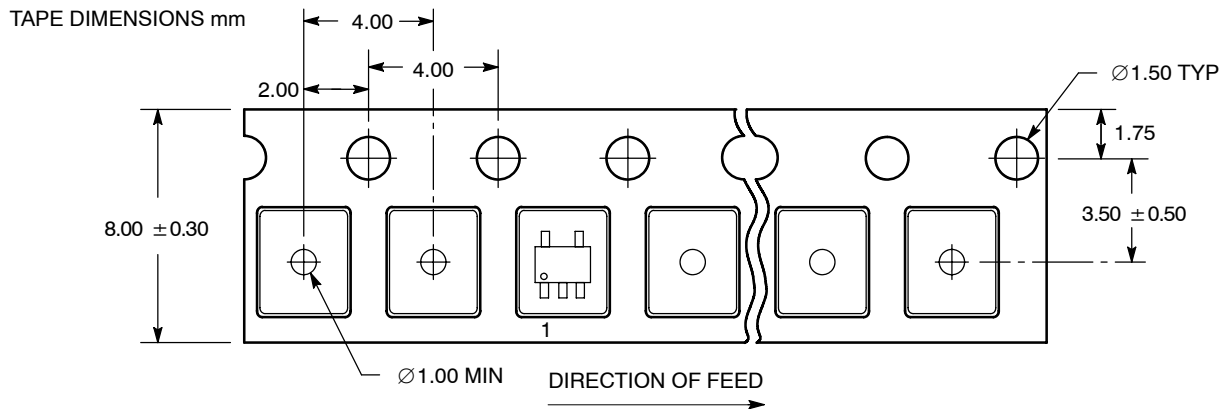
# MC74VHC1G50



**Figure 6. Tape Ends for Finished Goods**



**Figure 7. SC-70-5/SC-88A/SOT-353 DFT1 Reel Configuration/Orientation**



**Figure 8. SC-70/SC-88A/SOT-353 DFT2 and SOT23-5/TSOP-5/SC59-5 DTT1 Reel Configuration/Orientation**

# MC74VHC1G50

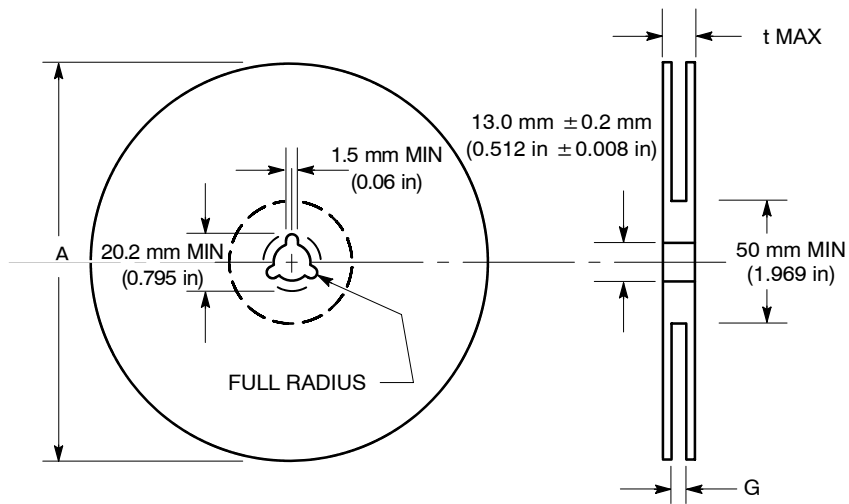


Figure 9. Reel Dimensions

## REEL DIMENSIONS

| Tape Size | T and R Suffix | A Max            | G   | t Max                |
|-----------|----------------|------------------|---|----------------------|
| 8 mm      | T1, T2         | 178 mm<br>(7 in) | 8.4 mm, + 1.5 mm, -0.0<br>(0.33 in + 0.059 in, -0.00) | 14.4 mm<br>(0.56 in) |

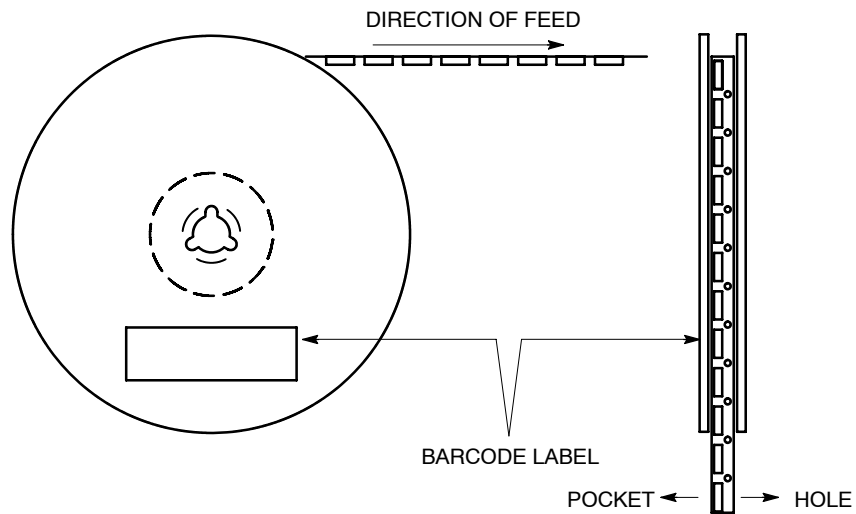
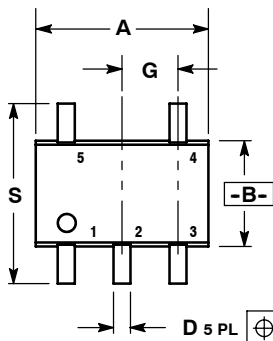


Figure 10. Reel Winding Direction

# MC74VHC1G50

## PACKAGE DIMENSIONS

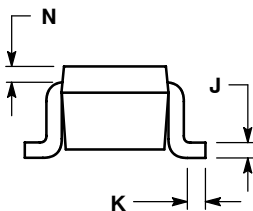
SC70-5/SC-88A/SOT-353  
 DF SUFFIX  
 5-LEAD PACKAGE  
 CASE 419A-02  
 ISSUE G



D 5 PL  $\oplus$  0.2 (0.008) M B M

- NOTES:
1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
  2. CONTROLLING DIMENSION: INCH.
  3. 419A-01 OBSOLETE. NEW STANDARD 419A-02.
  4. DIMENSIONS A AND B DO NOT INCLUDE MOLD FLASH, PROTRUSIONS, OR GATE BURRS.

| DIM | INCHES    |       | MILLIMETERS |      |
|-----|-----------|-------|-------------|------|
|     | MIN       | MAX   | MIN         | MAX  |
| A   | 0.071     | 0.087 | 1.80        | 2.20 |
| B   | 0.045     | 0.053 | 1.15        | 1.35 |
| C   | 0.031     | 0.043 | 0.80        | 1.10 |
| D   | 0.004     | 0.012 | 0.10        | 0.30 |
| G   | 0.026 BSC |       | 0.65 BSC    |      |
| H   | ---       | 0.004 | ---         | 0.10 |
| J   | 0.004     | 0.010 | 0.10        | 0.25 |
| K   | 0.004     | 0.012 | 0.10        | 0.30 |
| N   | 0.008 REF |       | 0.20 REF    |      |
| S   | 0.079     | 0.087 | 2.00        | 2.20 |



### SOLDERING FOOTPRINT\*

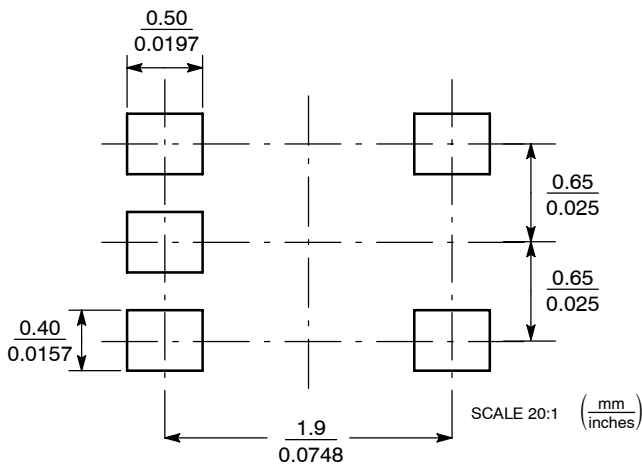


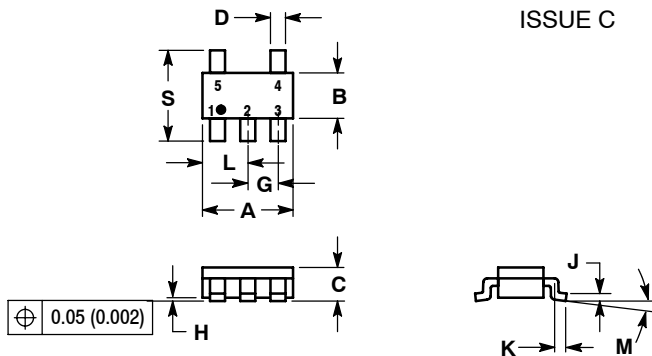
Figure 11. SC-88A/SC70-5/SOT-353

\*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

# MC74VHC1G50

## PACKAGE DIMENSIONS

SOT23-5/TSOP-5/SC59-5  
DT SUFFIX  
5-LEAD PACKAGE  
CASE 483-01  
ISSUE C



NOTES:

1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: MILLIMETER.
3. MAXIMUM LEAD THICKNESS INCLUDES LEAD FINISH THICKNESS. MINIMUM LEAD THICKNESS IS THE MINIMUM THICKNESS OF BASE MATERIAL.
4. A AND B DIMENSIONS DO NOT INCLUDE MOLD FLASH, PROTRUSIONS, OR GATE BURRS.

| DIM | MILLIMETERS |       | INCHES |        |
|-----|-------------|-------|--------|--------|
|     | MIN         | MAX   | MIN    | MAX    |
| A   | 2.90        | 3.10  | 0.1142 | 0.1220 |
| B   | 1.30        | 1.70  | 0.0512 | 0.0669 |
| C   | 0.90        | 1.10  | 0.0354 | 0.0433 |
| D   | 0.25        | 0.50  | 0.0098 | 0.0197 |
| G   | 0.85        | 1.05  | 0.0335 | 0.0413 |
| H   | 0.013       | 0.100 | 0.0005 | 0.0040 |
| J   | 0.10        | 0.26  | 0.0040 | 0.0102 |
| K   | 0.20        | 0.60  | 0.0079 | 0.0236 |
| L   | 1.25        | 1.55  | 0.0493 | 0.0610 |
| M   | 0           | 10    | 0      | 10     |
| S   | 2.50        | 3.00  | 0.0985 | 0.1181 |

## SOLDERING FOOTPRINT\*

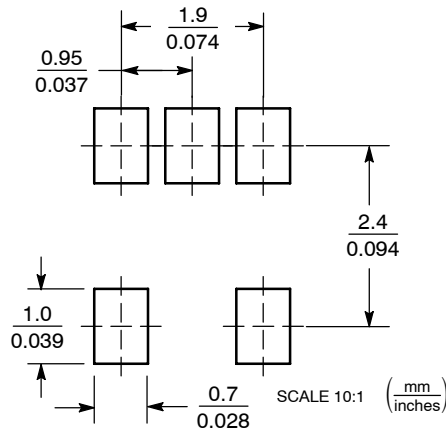


Figure 12. THIN SOT23-5/TSOP-5/SC59-5

\*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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- Экспресс доставка в любую точку России;
- Техническая поддержка проекта, помощь в подборе аналогов, поставка прототипов;
- Система менеджмента качества сертифицирована по Международному стандарту ISO 9001;
- Лицензия ФСБ на осуществление работ с использованием сведений, составляющих государственную тайну;
- Поставка специализированных компонентов (Xilinx, Altera, Analog Devices, Intersil, Interpoint, Microsemi, Aeroflex, Peregrine, Syfer, Eurofarad, Texas Instrument, Miteq, Cobham, E2V, MA-COM, Hittite, Mini-Circuits, General Dynamics и др.);

Помимо этого, одним из направлений компании «ЭлектроПласт» является направление «Источники питания». Мы предлагаем Вам помощь Конструкторского отдела:

- Подбор оптимального решения, техническое обоснование при выборе компонента;
- Подбор аналогов;
- Консультации по применению компонента;
- Поставка образцов и прототипов;
- Техническая поддержка проекта;
- Защита от снятия компонента с производства.



#### Как с нами связаться

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